# 3.3 V ECL +2 Divider

### Description

The MC100LVEL32 is an integrated ÷2 divider. The LVEL32 is functionally identical to the EL32, but operates from a 3.3 V supply.

The reset pin is asynchronous and is asserted on the rising edge. Upon power-up, the internal flip-flop will attain a random state; the reset allows for the synchronization of multiple LVEL32's in a system.

The V<sub>BB</sub> pin, an internally generated voltage supply, is available to this device only. For single-ended input conditions, the unused differential input is connected to V<sub>BB</sub> as a switching reference voltage.  $V_{BB}$  may also rebias AC coupled inputs. When used, decouple  $V_{BB}$ and  $V_{CC}$  via a 0.01  $\mu$ F capacitor and limit current sourcing or sinking to 0.5 mA. When not used,  $V_{BB}$  should be left open.

### Features

- 510 ps Propagation Delay
- 2.6 GHz Typical Maximum Frequency
- ESD Protection:
  - ♦ > 4 KV Human Body Model
  - ♦ > 200 V Machine Model
- The 100 Series Contains Temperature Compensation
- PECL Mode Operating Range:  $V_{CC}$  = 3.0 V to 3.8 V with  $V_{EE}$  = 0 V
- NECL Mode Operating Range:  $V_{CC} = 0$  V with  $V_{EE} = -3.0$  V to -3.8 V
- Internal Input Pulldown Resistors
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity:
  - ◆ Level 1 for SOIC-8
  - Level 3 for TSSOP-8
  - ◆ Level 1 for DFN-8
  - For Additional Information, see Application Note <u>AND8003/D</u>
- Flammability Rating: UL 94 V-0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count = 111 Devices
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



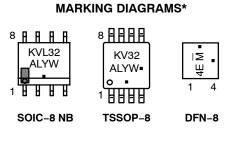
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SOIC-8 NB TSSOP-8 DFN<sub>-8</sub> **D SUFFIX** DT SUFFIX CASE 751-07 CASE 948R-02





- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- $\overline{M}$  = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

\*For additional marking information, refer to Application Note AND8002/D.

### **ORDERING INFORMATION**

Device	Package	Shipping†
MC100LVEL32DG	SOIC-8 NB (Pb-Free)	98 Units / Tube
MC100LVEL32DR2G	SOIC-8 NB (Pb-Free)	2500 Tape & Reel
MC100LVEL32DTG	TSSOP-8 (Pb-Free)	100 Units / Tube
MC100LVEL32DTR2G	TSSOP-8 (Pb-Free)	2500 Tape & Reel
MC100LVEL32MNR4G	DFN-8 (Pb-Free)	1000 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

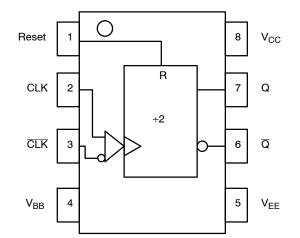


Figure 1. Logic Diagram and Pinout Assessment

### **Table 1. PIN DESCRIPTION**

Pin	Function
CLK*, CLK**	ECL Differential Clock Inputs
Q, <u>Q</u>	ECL Differential Data +2 Outputs
Reset*	ECL Asynch Reset
V <sub>BB</sub>	Reference Voltage Output
V <sub>CC</sub>	Positive Supply
V <sub>EE</sub>	Negative Supply
EP	(DFN8 only) Thermal exposed pad must be connected to a sufficient ther- mal conduit. Electrically connect to the most negative supply (GND) or leave unconnected, floating open.

\*Pin will default low when left open, per internal 75 K pull-down to

 $V_{EE}.$ \*\* Pin will default to  $V_{CC}/2$  when left open per internal 75 K $\Omega$  pull-down to  $V_{EE}$  and 75 K $\Omega$  pull-up to  $V_{CC}.$ 

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	PECL Mode Power Supply	V <sub>EE</sub> = 0 V		8 to 0	V
$V_{EE}$	NECL Mode Power Supply	V <sub>CC</sub> = 0 V		-8 to 0	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V <sub>EE</sub> = 0 V V <sub>CC</sub> = 0 V	$\begin{array}{l} V_I \leq V_{CC} \\ V_I \geq V_{EE} \end{array}$	6 to 0 –6 to 0	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V <sub>EE</sub> = 0 V V <sub>CC</sub> = 0 V	$\begin{array}{l} V_{I} \leq V_{CC} \\ V_{I} \geq V_{EE} \end{array}$	6 to 0 –6 to 0	V
l <sub>out</sub>	Output Current	Continuous Surge		50 100	mA
I <sub>BB</sub>	V <sub>BB</sub> Sink/Source			±0.5	mA
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			–65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	SOIC-8 NB SOIC-8 NB	190 130	°C/W
$\theta_{JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	SOIC-8 NB	41 to 44 ±5%	°C/W
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	TSSOP-8 TSSOP-8	185 140	°C/W
$\theta_{JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	TSSOP-8	41 to 44 ±5%	°C/W
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	DFN-8 DFN-8	129 84	°C/W
T <sub>sol</sub>	Wave Solder (Pb-Free)	< 2 to 3 sec @ 260°C		265	°C
$\theta_{JC}$	Thermal Resistance (Junction-to-Case)	(Note 1)	DFN-8	35 to 40	°C/W

Table 2. MAXIMUM RATINGS

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. JEDEC standard multilayer board - 2S2P (2 signal, 2 power)

			<b>−40°C</b>		25°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		29	35		29	35		31	36	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2)	2215	2295	2420	2275	2345	2420	2275	2345	2420	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2)	1470	1605	1745	1490	1595	1680	1490	1595	1680	mV
VIH	Input HIGH Voltage (Single-Ended)	2135		2420	2135		2420	2135		2420	mV
$V_{\text{IL}}$	Input LOW Voltage (Single-Ended)	1490		1825	1490		1825	1490		1825	mV
$V_{BB}$	Output Voltage Reference	1.92		2.04	1.92		2.04	1.92		2.04	V
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) V <sub>PP</sub> < 500 mV V <sub>PP</sub> ≥ 500 mV	1.2 1.4		3.1 3.1	1.1 1.3		3.1 3.1	1.1 1.3		3.1 3.1	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current CLK CLK	0.5 -600			0.5 -600			0.5 -600			μΑ

### Table 3. LVPECL DC CHARACTERISTICS (V<sub>CC</sub> = 3.3 V; V<sub>EE</sub> = 0.0 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary 1:1 with V<sub>CC</sub>. V<sub>EE</sub> can vary  $\pm 0.3$  V.

2. Outputs are terminated through a 50  $\Omega$  resistor to V<sub>CC</sub> – 2.0 V.

 V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V<sub>PP</sub>min and 1 V.

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current		29	35		29	35		31	36	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 2)	-1085	-1005	-880	-1025	-955	-880	-1025	-955	-880	mV
V <sub>OL</sub>	Output LOW Voltage (Note 2)	-1830	-1695	-1555	-1810	-1705	-1620	-1810	-1705	-1620	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)	-1810		-1475	-1810		-1475	-1810		-1475	mV
V <sub>BB</sub>	Output Voltage Reference	-1.38		-1.26	-1.38		-1.26	-1.38		-1.26	V
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) $V_{PP} < 500 \text{ mV}$ $V_{PP} \ge 500 \text{ mV}$	-2.1 -1.9		-0.2 -0.2	-2.1 -1.9		-0.2 -0.2	-2.1 -1.9		-0.2 -0.2	V
Ι <sub>ΙΗ</sub>	Input HIGH Current			150			150			150	μA
Ι <sub>ΙL</sub>	Input LOW Current CLK CLK	0.5 -600			0.5 -600			0.5 -600			μΑ

### Table 4. LVNECL DC CHARACTERISTICS (V<sub>CC</sub> = 0.0 V; V<sub>EE</sub> = -3.3 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary 1:1 with V<sub>CC</sub>. V<sub>EE</sub> can vary  $\pm$ 0.3 V.

2. Outputs are terminated through a 50  $\Omega$  resistor to V<sub>CC</sub> – 2.0 V.

3. V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V<sub>PP</sub>min and 1 V.

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f <sub>max</sub>	Maximum Toggle Frequency	2.2	2.5		2.4	2.6		2.6	2.8		GHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay CLK to Q (Differential) CLK to Q (Single-Ended) Reset to Q	350 300 440	500 500 555	530 580 640	370 320 450	510 510 540	550 600 650	410 360 480	540 540 580	590 640 680	ps
t <sub>RR</sub>	Reset Recovery	175	50		175	50		175	50		ps
t <sub>PW</sub>	Minimum Pulse Width Reset	500	300		500	300		500	300		ps
<b>t</b> JITTER	Random Clock Jitter (RMS)		2.0			2.0			2.0		ps
V <sub>PP</sub>	Input Swing (Differential Swing) (Note 2)	150		1000	150		1000	150		1000	mV
t <sub>r</sub> t <sub>f</sub>	Output Rise / Fall Times Q (20%-80%)	120	225	320	120	225	320	120	225	320	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1.  $V_{EE}$  can vary  $\pm 0.3$  V.

2. VPP(min) is input swing measured single-ended on each input in differential configuration.

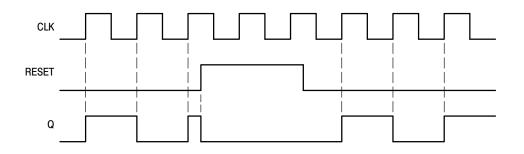


Figure 1. Timing Diagram

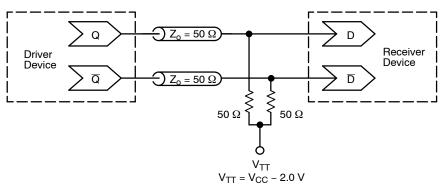


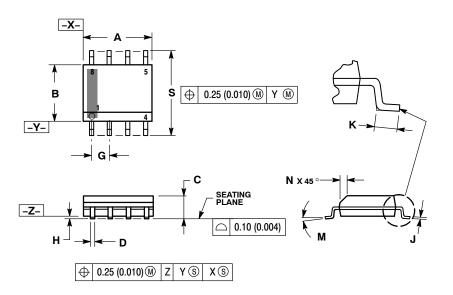
Figure 2. Typical Termination for Output Driver and Device Evaluation (See Application Note <u>AND8020/D</u> – Termination of ECL Logic Devices)

### **Resource Reference of Application Notes**

AN1405/D	-	ECL Clock Distribution Techniques
AN1406/D	-	Designing with PECL (ECL at +5.0 V)
AN1503/D	-	ECLinPS I/O SPiCE Modeling Kit
AN1504/D	-	Metastability and the ECLinPS Family
AN1568/D	-	Interfacing Between LVDS and ECL
AN1672/D	-	The ECL Translator Guide
AND8001/D	-	Odd Number Counters Design
AND8002/D	-	Marking and Date Codes
AND8020/D	-	Termination of ECL Logic Devices
AND8066/D	-	Interfacing with ECLinPS
AND8090/D	-	AC Characteristics of ECL Devices

### PACKAGE DIMENSIONS

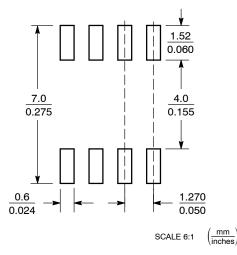
SOIC-8 NB **D SUFFIX** CASE 751-07 **ISSUE AK** 



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION. 6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIN	IETERS	INC	HES		
DIM	MIN	MAX	MIN	MAX		
Α	4.80	5.00	0.189	0.197		
В	3.80	4.00	0.150	0.157		
С	1.35	1.75	0.053	0.069		
D	0.33	0.51	0.013	0.020		
G	1.27	7 BSC	0.050 BSC			
н	0.10	0.25	0.004	0.010		
J	0.19	0.25	0.007	0.010		
к	0.40	1.27	0.016	0.050		
М	0 °	8 °	0 °	8 °		
Ν	0.25	0.50	0.010	0.020		
s	5.80	6.20	0.228	0.244		

SOLDERING FOOTPRINT\*

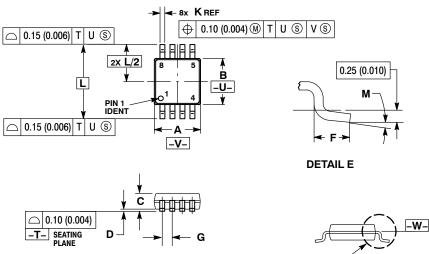


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### PACKAGE DIMENSIONS

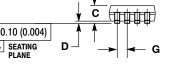
TSSOP-8 DT SUFFIX CASE 948R-02 **ISSUE A** 

DETAIL E



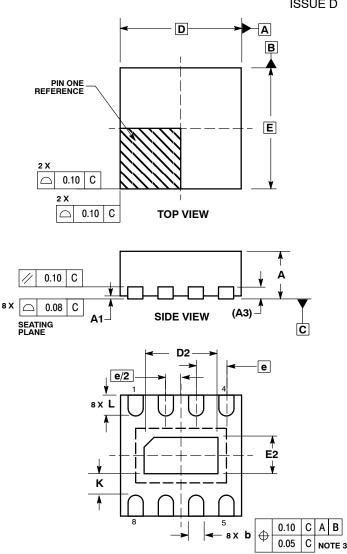
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	DIM	MIN	MAX	MIN	MAX		
ł	A	2.90	3.10	0.114	0.122		
t	B	2.90	3.10	0.114	0.122		
t	С	0.80	1.10	0.031	0.043		
Ī	D						
[	<b>F</b> 0.40 0.70 0.016 0.028						
[	G	G 0.65 BSC 0.026 BSC					
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NOTES:



### PACKAGE DIMENSIONS

DFN-8 **MN SUFFIX** CASE 506AA ISSUE D



#### **BOTTOM VIEW**

NOTES

1. DIMENSIONING AND TOLERANCING PER

З.

ASME Y14.5M, 1994 . CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL. COPLANARITY APPLIES TO THE EXPOSED 4

PAD AS WELL AS THE TERMINALS

	MILLIMETERS					
DIM	MIN	MAX				
Α	0.80	1.00				
A1	0.00	0.05				
A3	0.20	REF				
b	0.20	0.30				
D	2.00	BSC				
D2	1.10	1.30				
E	2.00	BSC				
E2	0.70	0.90				
е	0.50	BSC				
к	0.20					
L	0.25	0.35				

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